# The CMS pixel detector: ready for the future?

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## The Large Hadron Collider at CERN

#### Large Hadron Collider

#### Hadron: composite particle made of quarks held together by the strong force

CERN Prévessin

6.5 tera-electron volt (TeV) per proton beam

2x2800 bunches of protons 25 ns apart

SUISSI

beampipes!

.zmescience.com/wp-content/uploads/2015/05/cera-lhc-aerial.jpg

https://www.youtube.com/watch?v=NhXMXiXOWAA

protons

LINA

ATT

https://home.cern/sites/home.web.cern.ch/files/image/inline-images/old/lhc\_long\_1.jpg

oload wikimedia.org/wikipedia/commons/6/62/CERN\_LHC\_Proton\_Source.JPG

## **Detectors at the LHC**



#### ATLAS

A Toroidal LHC ApparatuS: 25 m x 25 m x 46m The largest volume detector ever constructed for a particle collider! Multipurpose detector.

A Large Ion Collider Experiment: specialized in heavy ion collisions and quark-gluon plasma: fraction of second after big bang





ALICE





**Compact Muon Solenoid** 

14000 tons: 1.5\* Eiffel tower weight, half the size of ATLAS: 15 m x 15 m x 21 m very compact! Largest superconducting solenoid magnet ever made

LHC beauty: A single-arm **forward** detector designed for the study of particles containing **b** or c quarks. 🌄

Other detectors: MoEDAL, TOTEM, LHCforward

100 meters underground in the CMS cavern

La.

LUX 153-12



CMS Experiment at the LHC, CERN Data recorded: 2016-May-11 21:40:47.974592 GMT Run / Event / LS: 273158 / 238962455 / 150





0.8 Barney, CERN, February 21



## One pixel detector



## Particle detection

Space radiation in

keV per pixel in x-y plane on a Timepix chip with a 300 μm thick silicon pixel

sensor.









## Ideal signal detection with silicon sensors

- A minimum ionizing particle (MIP) traveling through a fully depleted region (V<sub>FD</sub>) creates electron hole pairs
- The charges drift to opposite directions under the electric field
- Within nanoseconds, a signal is induced at the readout



p-in-n silicon sensor

One can measure  $V_{\rm FD}$  by scanning the bias voltage during data taking so that the  $V_{\rm FD}$  yielding optimal signal can be applied.

## The CMS phase 1 detector

## Plan for the LHC and CMS pixel





## DCDC power conversion in the pixel detector

- 1.9\*amount of channels compared to previous detector → more current
- Same cables: no space!
- Power loss ∝ current<sup>2</sup>
- Solution: keep current low over longer distance
  - → keep voltage high until close to endpoint





## DCDC power conversion in the pixel detector



- FEAST2.3: radiation hard ASIC developed by CERN
- Can operate in magnetic field of 3.8 T
- 1200+ converters made in Aachen using FEAST chip

## One half of the pixel barrel detector





High density interconnect (HDI): power, TBM

**Token bit manager: TBM** Clock and trigger distribution, ROC readout

Sensor: 285  $\mu m^2 \, n^+$  in n with 150 x 100  $\mu m^2$  pixels

Readout chip (ROC): 250 nm CMOS PSI46digv2 and PROC600. 8 bit digitization of signal above threshold. PROC600 for up to 600 MHz especially for innermost layer.





Counting room: next to CMS cavern

> To upstairs at up to 10Gb/s<sup>20</sup>



## Operating the CMS pixel detector





#### Detector performance



Data and time stamp are buffered until a trigger or reset arrives.

# Overall a high efficiency: good performance!

**Inefficiency** from synchronization loss between data and time stamp buffer at high and low rates:

- $\circ$  low L  $\sim$  1E33/cm<sup>2</sup>/s<sup>2</sup>
- $\circ$  high L > 1.4E34/cm<sup>2</sup>/s<sup>2</sup>
- solved by 70 Hz CMS reset rate

## Layer 1 chip PROC600: timing, crosstalk, inefficiency

- Layer 1 readout chip speed ½ clock faster than layer 2 ROC → not enough delay setting granularity: L1, L2 on same clock
- High thresholds resulting from crosstalk → "noise" hits

solved with software



## More problems with layer 1

- HV problem on the High Density Interconnect (HDI), the flex on the module: shorts in June 2018
- Stayed at 450 V in 2018





<u>From Danek</u> <u>Kotlinski</u>

## Stuck TBMs and malfunctioning DCDC converters



1: token bit manager (TBM) 30 single event upsets (SEUs)/fb<sup>-1</sup> in L1 transistor in TBM latch sets TBM to 'no readout' mode: "stuck TBMs" recovery only with **power** cycle. Lowest granularity: one

DCDC converter.



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## Radiation effects

## LHC: a challenging environment



Radiation effects are challenging for operations and performance:

- Damage and single event upsets (SEUs) in electronics
  - → false signals, chip damage
- Bulk defects cause change of space charge distribution
  - → bias voltage increase
- Increasing leakage currents and heat dissipation
- Charge trapping in sensor:
  - → decreasing charge collection efficiency

• neutron equivalent number of particles per unit area

## Not so ideal signal detection: radiation damage

Charges induced by an incident particle are collected with reduced efficiency as a result of radiation damage that causes:

- **Deformation** of the electric field
- **Trapping** induces screening of charge
- Diffusion or annealing deflects the path:
  Annealing
- Magnetic field, which changes with operational bias voltage and changing electric field, deflects the path:
   Lorentz angle





#### Radiation effects on depletion voltage



Phase-1 Pixel - Full depletion voltage vs days

Simulation with effective space charge Hamburg model ( $E_{eff}$ =1.21 eV), fluence from DPMJet + FLUKA 3.23.1.0

model parameters from Hambu

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#### Radiation effects in the forward pixel detector

On-module temperatures better understood than in barrel detector

Phase-1 Forward Pixel - Full depletion voltage vs day



Phase-1 Forward Pixel - Leakage current vs day

CMS Preliminary

Leakage current data

1.2

CMS FLUKA study v3.23.1.0

Forward Pixel Ring 1 Disk 1

z = 32 cm

33 Leakage current depends on fluence and temperature

## Cooling and temperatures

## $CO_2$ cooling

Important to understand detector temperatures for radiation effects:

- ✓ -22°C, option to go lower
- ✓ 1.7mm ø stainless steel cooling loops

remperature [°C

-12

-14

- $\checkmark$  wall thickness 50 $\mu$ m
- ✓ very lightweight



gradient of 4-5K along cooling loop efficient cooling but **no efficient heating** which can be problematic for targeted **annealing or safety** 



Increasing the flow did decrease some gradient but still a **non-negligible pressure drop** along cooling loop




# Work this long shutdown

## **Pixel** extraction







#### The CMS pixel detector was installed in 2017

## Detector on the surface



One can now see through CMS!



The long shutdown 2 (LS2) has started after two years of operation of this CMS phase 1 pixel detector. **Currently there are no collisions at the LHC.** 

Now cold in clean room. Cold is important! To prevent **reverse annealing** that worsens radiation damage.

# Maintenance in LS2



Photo courtesy of Mădălina Wittel







... and more prepare to make the most out of run 3!

# High luminosity LHC

# High luminosity → high precision



Much better precision for Higgs coupling strengths and measurements like  $B_s^0 \rightarrow \mu^+ \mu^ B \rightarrow \mu\mu$  measurements are expected to achieve  $6.8\sigma$ 

precision



# High luminosity LHC: a very challenging environment



# Requirements for the CMS tracker for high-lumi LHC

Must-haves:

- More radiation hard -> thinner or 3D sensors
- **Deal with high rates →** smaller pixels
- Low enough leakage current → **no thermal runaway**

Wishlist for good physics:

- High spatial **resolution**
- Good signal/noise
- High single pixel hit efficiency



# CMS tracker for the high luminosity LHC

In long shutdown 3, the entire CMS tracker will be replaced with one that fulfills the requirements for the high luminosity LHC.









## **Planar sensors**

- Used in present pixel detectors
- High production yield
- Large area sensors



# 3D sensors

- Collection and drift distance decoupled
- Lower chance of trapping
- Reduced depletion voltage: O(10) V
- Fast charge collection
- Option for innermost layer of CMS





# Charge sharing improves resolution

For physics results the resolution obtained with new pixel module is important:



Resolution improves with angle: charge sharing gives a weighted average + better resolution

# Pixel cell dimensions and resolution

- $25 \times 100 \ \mu m^2$  or  $50 \times 50 \ \mu m^2$ : charge sharing different
- Best resolution: cluster size of 2





50x5 um<sup>2</sup>

Current: 150x100 μm²

# Resolution for 25x100 $\mu$ m<sup>2</sup> pixels

- Optimal charge sharing is for 9.5°
- Best hit resolution
  2.68 µm before
  irradiation
- Best hit resolution 3.92  $\mu$ m for proton-irradiated sensor at  $\Phi_{eq} = 2.10^{15}/cm^2$



Average cluster size

## The CMS pixel detector: ready for the future!

The CMS pixel phase 1 detector has • delivered excellent data throughout 2017 and 2018 despite the challenges Test setups and temperature mockup • have proven very valuable The phase 1 pixel detector will get a new innermost layer R&D is ongoing to make the decision 0 for the phase 2 sensor type and pixel size: first results very promising!

	Fluence (order of magnitude)	Energy	Integrated Iumi
LHC	$\Phi_{eq} = 10^{15}/cm^2$	13-14 TeV	300/fb
HL-LHC	$\Phi_{eq} = 10^{16}/cm^2$	14 TeV	3000/fb
FCC	$\Phi_{eq} = 10^{18}/cm^2$	100 TeV	30000/fb
		12812-1	

More to come!

R&D continues for detectors beyond HL-LHC!

# Additional material

# DCDC converter story

# DCDC malfunctioning

Enclosed layout (ELT) vs linear transistors → can 'cut' leakage current path by adding ELT in series



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# DCDCs

Disconnected DCDCs: for safety switched off entire power supply (LV and HV). No DCDC broke in 2018!

"disabled"

Before

- SEU in transistor in TBM flipflop sets TBM to 'no readout' mode  $\rightarrow$  powercycle TBM
- Powercycled with DCDCs (lowest amount of modules) in 2017
- Increased leakage current in DCDCs after irradiation causes charging up of capacitor in disabled state - design mistake in layout around one transistor:
- High and low voltage group granularity not the same: damaged modules from HV on where DCDCs were broken  $\rightarrow$  LV off.



## Radiation effects: on-track cluster charge













**A→B**: CO<sub>2</sub> pressure is increased for transfer to the experiment **B→C**: temperature increases from heat exchange with returning CO<sub>2</sub> **C→D**: pressure inside the detector is reduced to reach onset of evaporation **D→E**: heat from the detector is absorbed **E→F**: CO<sub>2</sub> liquid/vapor mixture condensates on incoming colder CO<sub>2</sub> pipe **F→G**: CO<sub>2</sub> is cooled with main chiller

G: temperature in detector is regulated with pressure in accumulator: D-G low impedance system with <sup>∼</sup>constant pressure back to D

# Radiation damage in silicon

# Effects from radiation damage

Effects from radiation damage can be challenging in operation of detectors as well as for physics:

- Increasing leakage currents
- Charge accumulation in silicon oxide layers
- Single event upsets, in readout only → see electronics session
- Decreasing signal-to-noise ratios
- Changing depletion voltages
- Radiation induced activation of components



From Michael Moll

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p-in-n silicon sensor

# Microsocopic defects

• **Bulk damage**: non-ionizing energy loss (NIEL), e.g.:



• Frenkel pair: vacancy + interstitial

• **Surface damage**, or ionizing energy loss: not considered for silicon but important in silicon oxide



# Modeling radiation damage: the depletion voltage Hamburg model

Assumptions:

$$V_{\text{dep.}} = |N_{\text{eff}}| \cdot \frac{ed^2}{2\epsilon\epsilon_0}$$

- Little trapping
- No double junction
- 1 MeV neutron equivalence

Input:

$$\Delta N_{eff}(t) = N_{beneficial a.}(t) + N_{stable damage} + N_{reverse a.}(t)$$

$$dN_A^{\rm stable}/dt \propto \Phi(t)$$

- Fluence
- Temperature over time (in order to include annealing effects)
- Sensor thickness d, sensor material

Output: effective space charge  $N_{off}$  -> depletion voltage  $V_{dep}$ 

# Modeling radiation damage

Modeling of radiation damage is very important for data (b) (c) Leakage current Depletion voltage Trapping, CCI Increase of Creation of charged defects Shallow levels

 Hamburg model can serve to model leakage currents and depletion voltages

$$\Delta I_{leak}(t,T;\Phi_{eq}) = \alpha(t,T) \Phi_{eq}(r,z) V$$

 To model signal: need to include defect parameters from trapping in Poisson and transport equations like in technology computer-aided design (TCAD).





D(E): displacement damage function in

- 1 MeV
  neutron-equivalent,
  or
- NIEL cross section MeV mb
- Reference: 1 MeV neutron-equivalent at 95MeV mb

# Performance of CMS phase 2 sensor candidates



- For higher irradiation, more bias voltage is needed to reach the same efficiency
- Need 400V more bias for proton irradiated than for neutron irradiated sensors to achieve an efficiency of 99%





Effects from radiation damage:

- Leakage current increase
- Space charge distribution: bulk doping in undamaged sensors but contribution from defects after irradiation → change in operational
   voltage

Material dependent (oxygen-content) and particle-type-dependent

 Trapping → decreased charge collection efficiency From Michael Mol
# How to detect a particle?

#### Note when the muon arrives here .



Trigger: do we want to choose?

through CMS

#### CMS and ATLAS pixel detectors in LS2



		phase 1 < 2024	phase 2 >= 2024
Phase $1 \rightarrow 2$ <u>CMS pixel layout</u> <u>CMS-TDR-011</u> CMS TDD 014	Disks, layers, reach	4 layers, 3 disks to <mark>η=2.5</mark>	4 layers, 12 disks to <b>η=3.8</b>
	Number of pixels	124 · 10 <sup>6</sup>	1949 · 10 <sup>6</sup>
	Pixel size	100×150 μm²	100×25 μm², 50×50 μm²
<u>CMS-TDR-014</u>	Active silicon area	1.85 m <sup>2</sup>	4.9 m <sup>2</sup>
Module stacking for both phase 1 and phase 2:	Readout chips	PSI46dig/PROC600 250 nm	RD53B = CROC 65 nm
	Number of ROCs	1856 · 16 ROCs	1156 · 2 + 2736 · 4 ROCs
Flex print	Sensor type	n⁺-n planar 285 µm	n⁺-p planar/3D 100-150 µm
wire bonded glued sensor bump bonded ROCs	Aaterial budget Mechanical support	<ul> <li>1.6</li> <li>Phase-1 Tracker</li> <li>CMS Simulation</li> <li>1.4</li> <li>1.2</li> <li>1.4</li> <li>1.2</li> <li>1.4</li> <li>0.8</li> <li>0.6</li> <li>0.4</li> <li>0.2</li> <li>0</li> <li>0.5</li> <li>1</li> <li>1.5</li> <li>2</li> <li>2.5</li> <li>3</li> <li>3.5</li> <li>4</li> </ul>	1.6 Phase-2 Tracker informed in sensors     1.4 Between IT and OT     1.2 Between IT and OT     1.1 Between IT an

#### With or without bias dot

- Efficiency 97% at vertical incidence
- Efficiency 99.7% at 34°
- Efficiency loss at bias dot
- disappears only at large angles (27°)
- Almost vertical incidence in forward pixel detector (TFPX)
- Without bias dot no test of sensors before bump bonding
- Possible to use small test sensors with bias dot for wafer acceptance



#### Sensor design

Top view of 25x100  $\mu$ m<sup>2</sup> n<sup>+</sup>p (n<sup>+</sup>  $\rightarrow$  collecting electrons) sensor:

Cut image along red arrow:





В

DUT

С

### Resolution vs incidence angle

- **Optimal charge** sharing is for 9.5°
- Best hit resolution 2.68 µm before irradiation
- Best hit resolution 3.92 µm for proton-irradiated sensor at  $\Phi_{eq} = 2.10^{15}/cm^2$

## Future LHC detectors







